

Product Features

Product Model:	NM10L16B
Dimension:	182mmx182mm±0.25mm
Cell Thickness:	130μm±15μm
Front side:	0.03±0.015mm wide bus bars, Silicon nitride, aluminum oxide
Back side:	0.03±0.015mm wide bus bars, Silicon nitride

Electric Performance

Efficiency(%)	Power Pmpp(W)	Max.Power Current Impp(A)	Short Circuit Current Isc(A)	Max.Power Voltage Vmpp(V)	Open Circuit Voltage Voc(V)
25.2	8.32	13.518	14.078	0.633	0.724
25.1	8.29	13.475	14.035	0.632	0.723
25.0	8.25	13.440	14.001	0.631	0.722
24.9	8.22	13.405	13.965	0.630	0.722
24.8	8.19	13.370	13.930	0.629	0.721
24.7	8.15	13.335	13.895	0.628	0.720
24.6	8.12	13.300	13.860	0.627	0.719
24.5	8.09	13.265	13.825	0.627	0.718
24.4	8.06	13.230	13.790	0.626	0.717
24.3	8.02	13.195	13.755	0.625	0.717
24.2	7.99	13.155	13.715	0.624	0.716
24.1	7.96	13.115	13.675	0.623	0.715
24.0	7.92	13.079	13.633	0.622	0.714

- Under standard test condition: 1000W/ m², AM 1.5G, 25°C
- Illustration: 25.0% actual range: 25.0%~25.1%
- Specifications and data are provided for reference only and will be separately notified if there is any change

Temperature Coefficients

Current Temperature Coefficient	Tkcurrent: +0.045%/K
Voltage Temperature Coefficient	Tkvoltage: -0.25 %/K
Power Temperature Coefficient	Tkpower: -0.29%/K

